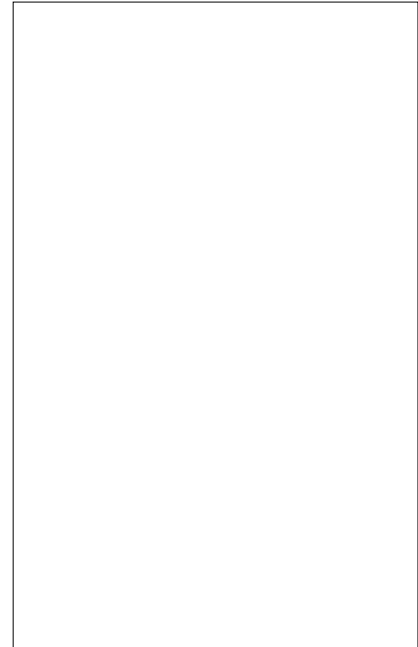




With high ability to withstand the shock loading of large current, JCT1640SJ SCR provides high dV/dt rate with strong resistance to electromagnetic interference. It is especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc. Package TO-247J is RoHS compliant.



Parameter	Symbol	Value	Unit
Storage junction temperature range	T _{stg}	-40-150	

Peak gate power	P_{GM}	20	W
Peak pulse voltage ($T_j=25$; non-repetitive,off-			

FIG.1: Maximum power dissipation versus RMS on-state current

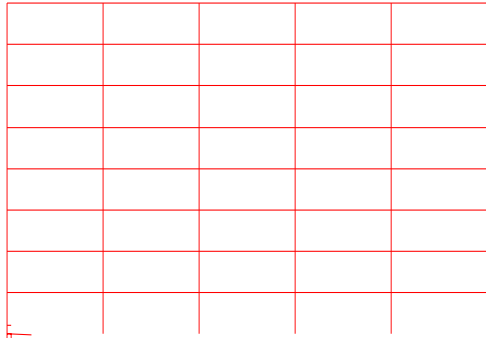
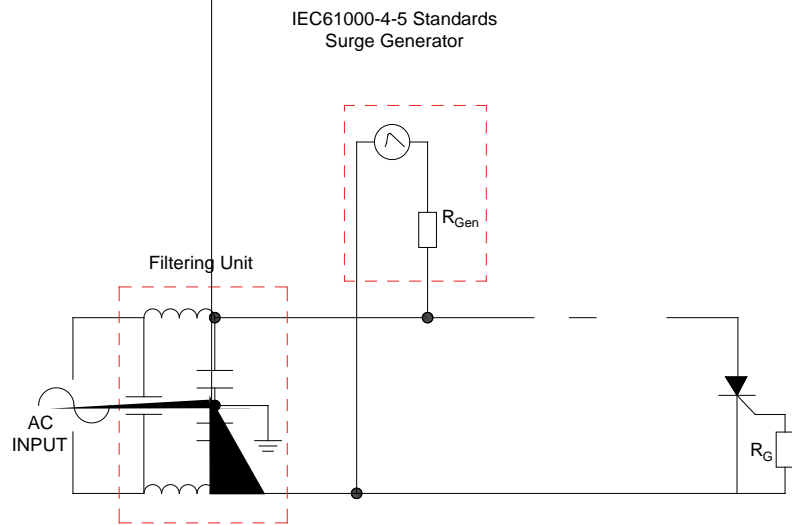
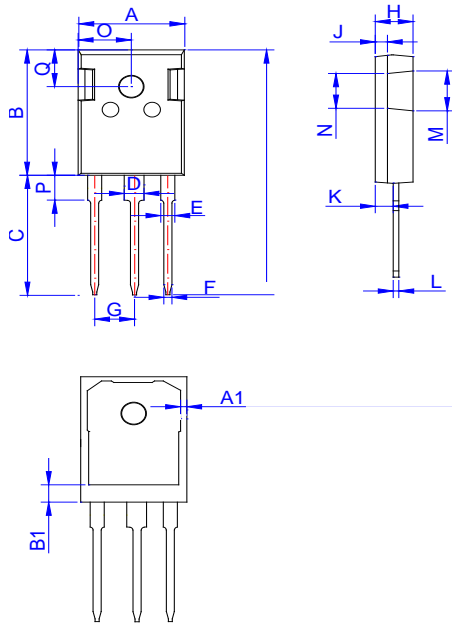


FIG.2: RMS on-state current versus case temperature

FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.




Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)	Packagage
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Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.50		16.10	0.610		0.634
A1	1.15		1.55	0.045		0.061
B	20.80		21.20	0.819		0.835
B1	3.10		3.50	0.122		0.138
C	19.70		20.30	0.776		0.799
D	2.90		3.30	0.114		0.130
E	1.90		2.30	0.075		0.091
F	1.00		1.40	0.039		0.055
G		5.44			0.214	
H	4.80		5.20	0.189		0.205
J	1.90		2.10	0.075		0.083
K	2.20		2.50	0.087		0.098
L	0.41		0.79	0.016		0.031
M	3.70		3.90	0.146		0.154
N	3.55		3.70	0.140		0.146

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